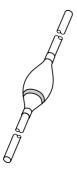
DISCRETE SEMICONDUCTORS

DATA SHEET



BYX134GHigh-voltage car ignition diode

Product specification Supersedes data of 2000 Feb 29

2001 Oct 02





High-voltage car ignition diode

BYX134G

FEATURES

- · Glass passivated
- · High maximum operating temperature
- · Low leakage current
- · Excellent stability
- · Guaranteed avalanche energy absorption capability.

APPLICATIONS

- · Car ignition systems
- Automotive applications with extreme temperature requirements.

DESCRIPTION

Rugged glass package, using a high temperature alloyed construction.

The SOD61AC2 is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

The package is designed to be used in an insulating medium such as resin, oil or SF6 gas.

The BYX134G is marked with a blue cathode band on the body.

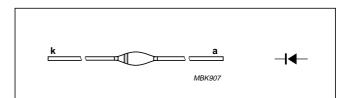


Fig.1 Simplified outline (SOD61AC2) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|-------------------------------------|---|------|------|------|
| V _{RRM} | repetitive peak reverse voltage | | _ | 4 | kV |
| V _{RWM} | crest working reverse voltage | | _ | 4 | kV |
| I _{F(AV)} | average forward current | | _ | 50 | mA |
| I _{FRM} | repetitive peak forward current | | _ | 500 | mA |
| I _{RSM} | non-repetitive peak reverse current | t = 100 μs triangular pulse; T _{j max} prior to surge | _ | 50 | mA |
| T _{stg} | storage temperature | | -65 | +200 | °C |
| Tj | junction temperature | continuous | _ | 175 | °C |
| T _i | junction temperature | max. 30 min. | _ | 200 | °C |

CHARACTERISTICS

T_i = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|-------------------------------------|---|------|------|------|
| V _F | forward voltage | I _F = 10 mA | 5 | 7 | V |
| V _{(BR)R} | reverse avalanche breakdown voltage | I _R = 100 μA | 5.5 | 7.5 | kV |
| I _R | reverse current | $V_R = V_{RWMmax}$; $T_j = 175 ^{\circ}C$ | _ | 30 | μΑ |

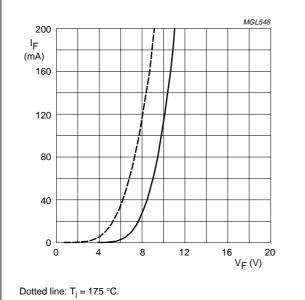
THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|---|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | $T_{amb} = T_{leads}$; lead length = 10 mm | 90 | K/W |

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GRAPHICAL DATA



Dotted line: $T_j = 175 \,^{\circ}\text{C}$ Solid line: $T_j = 25 \,^{\circ}\text{C}$.

Fig.2 Forward current as a function of maximum forward voltage.

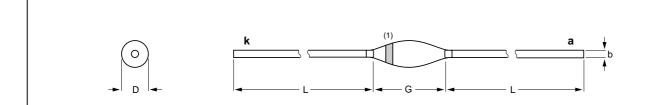
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PACKAGE OUTLINE

Hermetically sealed glass package; axial leaded; 2 leads

SOD61AC2



DIMENSIONS (mm are the original dimensions)

| UNIT | b | D max. | G max. | L min. | |
|------|-----|-----------|-----------|-----------|--|
| mm | 0.6 | 2.5 | 8.3 | 30.4 | |

0 2.5 5 mm scale

Note

1. The marking band indicates the cathode.

| OUTLINE | OUTLINE REFERENCES | | EUROPEAN | ISSUE DATE | | |
|----------|--------------------|-------|----------|------------|------------|------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE |
| SOD61AC2 | | | | | | 98-12-04 |

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DATA SHEET STATUS

| DATA SHEET STATUS(1) | PRODUCT STATUS ⁽²⁾ | DEFINITIONS |
|----------------------|----------------------------------|--|
| Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product. |
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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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NOTES

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NOTES

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